NSN 5961-01-058-7808

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-058-7808 **Inclosure Material:** Metal **Overall Length:** Between 0.085 inches and 0.110 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.095 inches and 0.110 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-17 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.0 on voltage, forward voltage drop, dc **Current Rating Per Characteristic:** 1.00 milliamperes source cutoff current preset and 2.00 milliamperes forward current, average peak **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Test Data Document:** 30003-446as154 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**